Photocatalytic Degradation of Orange II by Active Layers of Ag-Doped CuO Deposited by Spin-Coating Method

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Abstract: For water purification in our daily life at low cost and in the goal to study the effect of doping elements for heterogeneous photocatalysis application, thin layers of Ag doped CuO, (5, 15, 25 and 50 wt.%) were prepared by a sol-gel method on a glass substrate for photocatalysis. The structural, morphological, optical and electrical characteristics of these layers have been studied. The results of X-ray diffraction (XRD) proved that there was a monoclinic phase structure in the direction (-111). This result indicated that thin films are polycrystalline. It was confirmed by infrared spectra (IR). In the case of Ag doping, scanning electron microscope (SEM) revealed a change in the shape of the granules with large and inhomogeneous sizes. Granules were spherical in the case of pure copper oxide. The energy gap decreases from 2.17 eV to 1.25 eV with the increasing doping. The improved capacitance is explained in terms of Ag particles present in CuO nanostructures giving a good electrical conductivity. The doping effect of Ag ions has improved the photocatalytic property of the CuO. It was tested for organic dye cleaning with Orange II. In addition, the presence of pores on the surface of Ag:CuO thin films and a reduce energy gap enables the creation of a greater number of •O and •OH that leads to eliminate the dye and give a transparent solution. A 50 wt.% Ag doping showed a high photoactivity (43%) after 5h compared to a pure CuO thin film (27% of degradation rate) for the same time.

1. Introduction

The textile industry is known to be polluting because its discharges consist of recalcitrant organic molecules that cannot be treated by conventional methods of decontamination. Synthetic dyes, 15% of which consist of nitrogen dyes, are among the most important sources of water pollution[1]. Despite great efforts in wastewater treatment, it is still unfortunately estimated that only 60% of the polluted water is sent to the treatment plant, and the rest is discharged into natural environment. One of the most alarming phenomena is the increasing accumulation of recalcitrant substances that are difficult to eliminate in water [2]. The situation is exacerbated by the lack or inadequacy of appropriate water treatment systems able to reduce the concentration of toxic substances that are chronic chemical hazards [3]. Organic pollutants present in wastewater, such as dyes, petroleum, and pharmaceuticals, are an environmental problem in modern society [4]. Organic pollutants in water have the potential to have a negative impact on health and increase the risk of chronic diseases. Moreover, in many countries pollution from textile industry discharges is heavily spread with dyes [5]. Dyes are often used in excess to improve colors; As a result, wastewater is highly concentrated in pigments, making it difficult to environmentally apply degrading biological treatments [6].

It is therefore necessary to find an effective method to remove these pollutants from wastewater from the textile, tanning or printing industries. A number of procedures and techniques including membrane filtration, adsorption, coagulation or flocculation, electrochemical oxidation processes and biodegradation have been documented [7]. More than 15% of the dyes produced worldwide for the textile industry are azo dyes such as Orange II (OII). Azo dyes are the largest and most versatile class of organic dye-stuffs. These contain one or more azo bonds (-N=N-) as a chromophore group in association with aromatic structures containing functional groups such as -OH and -SO₃H [4]. The complex aromatic structures of azo dyes make them more stable and more difficult to remove from the effluents discharged into the water bodies [8]. Thus, the removal of these dyes from wastewater is an important target from the environmental point of view. Currently, some typical non-destructive treatments, such as integrated processes that combine different combinations of biological, physical and chemical whitening, are used to reduce the amount of these pigments, which are essentially non-biodegradable and toxic. OII is an azo dye for textiles that resists fading by light, common acids and bases [9]. Alternative names for OII are Acid Orange 7 and Acid Orange II [10]. Heterogeneous photo catalysis, which allows the elimination of organic pollutants such as dyes while leading to complete mineralization, seems to be an alternative technology. The main factors influencing the photocatalytic process are the characteristics of the molecule to be broken down, the light source and the type of semiconductor acting as the photocatalyst (gap and texture) [11].

The sol-gel method makes it possible to produce a wide variety of oxides in different configurations: monoliths [12], thin films [13] and powders [14]. This process is very attractive, because it gives the possibility of diversified shaping of materials. It is used in several technological fields, optics, electronics and biomaterials. This method has the advantage of using soft chemistry; it makes it possible to obtain very pure and stoichiometric materials. The solution - gelation consists of a solution based on precursors in the liquid phase which is transformed into a solid by a sum of chemical reactions of the polymerization type at room temperature. Thin layers can be manufactured and prepared by several deposition techniques such as spray pyrolysis [15], dipcoating [16] and spin-coating [17], DC reactive sputtering [18] and thermal evaporation [19]. The last one is an inexpensive technique that allows a variety of materials to be obtained. The main advantages of this method are the good homogeneity, the ease of controlling the chemical compositions, the used heat treatment at low temperature (400-600 °C) and the good optical method [15].

In previous studies, Ag-CuO thin films were successfully used for photodegradation of dyes due to the recycling ability of microgels [6, 20]. Also a significant visible-light-driven photocatalyst for environmental remediation was obtained [21]. For this reason, the present study has been focused on the se effective elements (Ag, CuO).

The use of Copper oxide (CuO) in the photocatalytic destruction of environmental organic contaminants has attracted considerable interest. So far, the CuO photocatalyst has been efficiently produced in a variety of morphologies, including nanorods, nanoplates, nanotubes, hollow microspheres, microsprays, and nanowires [22]. CuO is an excellent candidate for semiconductor catalysts [21] and has advantages of being non-toxic, economical and environmentally friendly. The simple oxide formation makes the material attractive [23]. Due to the availability of its components in nature, its inexpensive manufacturing, superior thermal stability and electrochemical characteristics, it is an excellent candidate for semiconductor photocatalysts [22]. In addition, it has good optical and electrical properties and a high conductivity [24]. CuO is crystallized in a tenoritelike monoclinic structure with lattice parameters a = 4.6Å, b = 3.4Å, c = 5.1Å and $\beta = 99.2$ Å [25], a direct band gap (Eg = 1.2 to 2.2 eV) [26], a refractive index = 1.4 and an ionic radius 0.73Å [27]. The copper oxide films were prepared used in a number of applications such as gas sensor [28], antibacterial activity [29], solar cell [30] and photocatalysis [31]. Copper (Cu) has different oxidation states, such as Cu¹⁺, Cu²⁺ and Cu³⁺, which makes it equally promising for hole and electron doping. Nowadays, CuO is used as a photocatalyst, antioxidant, and drug delivery agent and imaging mediator in the field of biomedicine [32-34].

Ag atom doping has been widely attracted by researchers due to its novel applications in high density optical storage devices [35], gas sensors [36], photovoltaic cells [37], photodiodes and antibacterial coatings [38, 39]. Recently, silver oxide (Ag₂O) with a low energy bandgap (1.3 eV)

has received more attention in the practical photocatalytic application, due to ist great capacity in absorbing NIR light with out further process [40]. Moreover, on the basis of its relative high VB edge (1.5 eV vs NHE), it is feasible to drive necessary oxidation reaction for the split of water or degradation of organic pollutant molecules [41]. In order to determine the doping efficiency and their impact on photocatalysis, the application of photocatalysis by the degradation of OII under UV irradiation with catalysts in thin layers of CuO doped with Ag prepared by a sol-gel spin coating method is studied. The obtained results show that the use of thin layers of CuO doped with Ag enhanced the photocatalyzed degradation due its optical property and its small energy gap compared to pure CuO.

2. Experimental Study

2.1. Materials

Dehydrated copper acetate(Cu(CH₃COO)₂.2H₂O), absolute ethanol (C₂H₆O; purity96%)and monoethanolamine (MEA;NH₂CH₂CH₂OH \geq 98%) are used for the prepared solution. Silver nitrate (AgNO₃; purity 99%)is used for doping.OII (C₁₆H₁₁N₂NaO₄S; OII)as organic dye for photocatalysis application is provided by Sigma-aldricht.

2.2. Preparation of thin layers

The thin layers were deposited by the sol-gel spin coating method and consists in a thin film of a solution deposited on a glass substrate ($2cm \times 2 cm$)by centrifugation. In order, to prepare the 0.2M solution the dehydrated copper acetate precursor is dissolving in absolute ethanol. For studying the effect of doping rate by Ag on the thin layers of CuO, four different silver percentage solutions of $(n(Ag)\ n(Cu))*100\% = X\%$)with X= 5, 15, 25 and 50 with silver nitrate precursor AgNO₃ were prepared. A volume of monoethanolamine (MEA) was added in a molar ratio (n (MEA) \ n (sol) = 3). The solution was then heated under magnetic stirring at 70°C for 2 h.

All substrates were cleaned with methanol and distilled water for 5min and then dried, put in the oven at a temperature of 50°C for 10min. The spin-coating precursor solutions (2ml using a syringe) were dropped on substrates with a rotating speed of 3000 rpm for 30 s, followed by drying after each deposition at 250°C for 10 min in the oven. This cycle was repeated 4 times. Then a calcination in the oven was done at 500°C for 2 h.

2.3. Characterization techniques

In the goal to study the structural properties of thin layers of pure and Ag-doped CuO, XRD (Schimadzu Brucker AXS D8 ADVANCE type with a Cu K α radiation diffractometer ($\lambda = 1.54$ Å)) was used. The absorption spectra of the photocatalysts were obtained with a UV – visible spectrophotometer (model V-750) in the wavelength range 250-900 nm. The morphology of the films was examined using an environmental scanning electron microscope SEM type Thermo scientific Prisma E. The IR transmission spectra were recorded using a VERTEX 70 spectrophotometer in the spectral range [400 – 3600] cm⁻¹. The electrical properties were done with a four-point measuring device, JANDEL model, connected to a Keithley 2400 source meter.

3. Results and Discussion

3.1. X Ray Diffraction

Figure (1) represents the XRD spectra of thin films of Ag-doped CuO (Ag:CuO) recorded in the 2θ range from 25° to 70° . it presents several diffraction peaks attributed to the following crystal planes (110), (-111),(200),(-202), (020), (202),(-113),(-311),(220). The results are in agreement with the

JCPDS file code 00-041-0254 and confirm the presence of a tenorite phase of monoclinic structure, which belongs to space group C₂/c. After Ag doping exceeding 5%, there are additional peaks corresponding to the presence of the related secondary phases in the doped CuO films. The existence of the Ag₂O phase given by the four diffraction peaks found at the values $2\theta = 27.77^{\circ}, 38.26^{\circ}, 54.68^{\circ}$, and 64.55° correspond to the planes (110), (200), (211), (311) respectively and agree well with the JCPDS file (code00-041-1104). The peak (440) is in agreement with the JCPDS card (code00-040-0909) indicating the formation of silver oxide Ag₂O₃.

Because of an addition of Ag atoms, there is a definite shift in the position of these peaks towards lower angles. This shift indicates that Ag atoms of ionic radius 1.15 Å occupied the substitutional site of the Cu^{2+} atoms of ionic radius 0.73Å [42, 43] and involve a dilation in the CuO crystal lattice.



Fig.1.XRD spectra of thin layers of Copper oxide doped with different percentages of silver.

The crystallite sizes are nanometric varying from 16 nm to 24 nm and increase with the increase of doping thanks to the ionic radius of the silver atom (Fig.2). Similar results have been found in several studies of increasing crystal size of CuO doped with silver [44, 45]. Ag doping CuO improved the crystallinity of these layers with an increase in the crystal size and a decrease in strain. The crystallite sizes of these layers are illustrated in Table 1 and were calculated with the Scherrer's equation [46]:

$$D = \frac{0.9 \cdot \lambda}{\beta \cdot \cos\theta} \tag{1}$$

where D is the size of the crystallites, λ the wavelength of the incident ray, β the width at half maximum (FWHM) and θ the Bragg diffraction angle.

The micro-strain (ϵ) created in the thin films was calculated by relation ship[47]:

$$\varepsilon = \frac{\beta \cdot \cos\theta}{4} \tag{2}$$

Table 1. The crystallite size of the samples							
Phases	Plan	2θ (°)	θ(°)	FHWM	β (rad)	D (nm)	ε. 10 ⁻²
	(hkl)			β(°)			
CuO	(-111)	35.561	17.781	0.493	0.0086	16	0.215
Ag :CuO (5%)	(-111)	35.526	17.763	0.378	0.0066	21	0.165
Ag :CuO (15%)	(-111)	35.583	17.792	0.361	0.0063	22	0. 157
Ag :CuO (25%)	(-111)	35.486	17.743	0.344	0.0060	23	0.150
Ag :CuO (50%)	(-111)	35.573	17.787	0.326	0.0057	24	0.142



Fig. 2. Variation of crystallite size and FWHM of Ag:CuO samples as a function of the doping rate.

In order to know the change of axes (x, y), the lattice parameters ($a \neq b \neq c$, $\alpha = r = 90^{\circ} \neq \beta$) of the monoclinic structure of CuO were calculated using the following equations[48, 49]:

$$\frac{1}{d^2} = \frac{1}{\sin^2\beta} \left(\frac{h^2}{a^2} + \frac{k^2 \sin^2\beta}{b^2} + \frac{l^2}{c^2} - \frac{2hl\cos\beta}{ac} \right)$$
(3)

From the lattice parameter values indicated in table 2, it is noted an increase of lattice parameters (a, b), angles β and volumes of the crystallattice in all the thin films doped with silver. This result indicates the presence of a dilation of the lattice.

Table 2. The lattice parameters a, b and c					
Phases	a (Å)	b (Å)	c (Å)	β (°)	v (Å ³)
CuO	4.698	3.417	5.119	99.41	80.71
Ag :CuO (5%)	4.728	3.426	5.079	99.47	81.14
Ag :CuO (15%)	4.709	3.426	5.075	99.44	80.94
Ag :CuO (25%)	4.709	3.426	5.102	99.60	81.23
Ag :CuO (50%)	4.691	3.416	5.098	99.50	80.81

3.2. SEM Analysis

The study of the surface morphology by the SEM was carried out on the thin films of Ag-doped CuO. all the films showed a dense deposition and the surfaces are covered with almost a homogeneous and uniform grain size which clearly show the formation of a crack-free surface.

Figure 3 shows nano-spherical grains in the case of pure copper oxide. When the doping is present; there is a clear change in the shape of the grains after the addition of Ag. It is observed from SEM images that this change is strongly dependent on the percentage of doping. Moreover, the presence of large pores and in greater number with an increase in the doping rate confirms that Ag gives a more porous surface. It was also observed that there was an increase in the number and in the average size of pores. The value of the pore sizes changed from 43 nm (for pure CuO) to 193 nm (with 50 wt.% Ag:CuO). The addition of silver into CuO has contributed significantly to the increase in the percentage of pores within the granules and induced the capture of a larger number of impurities in the dye.





Fig.3. SEM image of various prepared samples. CuO (a),5 % Ag:CuO (b),15 % Ag :CuO (c) 25 % Ag:CuO (d), 50 % Ag:CuO (e),zoom of4μm x 4μm CuO (1),5 % Ag:CuO (2),15 % Ag:CuO (3), 25 % Ag:CuO (4),zoom of 2μm x 2μm 50 % Ag:CuO (5).

3.3. EDX Analysis

In order to confirm the presence of silver doping and the chemical composition of the thin layers, a EDX analysis was used. The spectra of Ag:CuO thin films with different doping ratios are shown in Table3. The Cu and O are clearly visible throughout the samples. The presence of additional Ag element also increases with the increase in the doping rate (1.28% fordoping with 15% Ag, 33.83 % for doping with 25% Ag and 38.03% fordoping with 50% Ag).Except for the rate of 5%Ag, silver was not sensed and this could be due to the low added rate of doping.

This result is in good agreement with the XRD results and confirms the production of CuO and Ag_2O on the brightening of the glass substrate.



Fig 4. EDX analysis spectrum of for thin films of CuO undoped and doped with silver.

Table 3. Percentage of atoms present in EDX spectrum.					
Phases	Cu%	O%	Ag%		
CuO	44.04	55.96	0		
Ag :CuO (5%)	58.36	41.62	0.02		
Ag :CuO (15%)	43.6	55.12	1.28		
Ag :CuO (25%)	18.61	47.56	33.83		
Ag :CuO (50%)	6.06	55.91	38.03		

f ato 2 D nt in FDX otr **m** 11 - 4 -

3.4. Vibrational Spectroscopy

The IR technique has been used to characterize thin films in order to gain a better understanding of the chemical compositions of the samples and the interactions that determine the attributes of the samples. Infrared (IR) spectra of undoped and Ag-doped CuO thin layers were recorded in the range 400-3000 cm⁻¹. Figure 5 shows, several absorption bands clearly identified. The absorption peaks detected at 472, 616, 667 and 718 cm⁻¹ correspond to Cu-O bonding in the characteristic stretching vibrations of CuO [50].

After doping with silver (15%, 25% and 50%), we notice a big difference in the absorption spectra in the 400-1100cm⁻¹range. The peaks of708 cm⁻¹,804 cm⁻¹,866 cm⁻¹ and 1147 cm⁻¹ are characterized by Ag-O binding and the other peak of 460cm⁻¹ characterized by Ag binding Ag-O-Ag [39].A strong bond is observed peak at 1742cm⁻¹ and represents the mode of C=O bond stretching vibrations. The peaks at 1641 cm⁻¹ corresponding to the vibration of the H-O-H bond which are associated with the vibration mode hydroxyl groups bound to adsorbed water [51].The bands observed around 1110 cm⁻¹ and 1155cm⁻¹can be attributed to the presence of asymmetric Si-O-Si stretching vibrations [52].



Fig.5.Infrared spectra of the Ag doped CuO with different percentage

3.5. Optical properties

3.5.1. Absorbance spectra

Thin layers of undoped and Ag-doped CuO were optically analyzed by UV Vis spectrophotometer. Figure 6 depicts the absorption spectra performed in the 250 - 900nm wavelength range. All spectra show absorbing in the visible and near IR [53]. It should be observed that the thin layers of pure CuO exhibit the lowest absorbance compared to the samples after doping. The addition of Ag with different percentages in CuO thin films significantly increased the absorption.

The absorption spectra showed strong absorption peaks around 310 nm and 360 nm with an absorption edge around 750 nm which corresponds to the CuO band transition. this shows that CuO films are crystalline [54]. It is observed that the absorption peaks of the thin layers of Ag:CuO is shifted to a higher wavelength corresponding to a decrease in the value of the band gap [55]. The absorption is maximum for thin films of Ag doped in the visible range. For pure copper oxide the absorption is maximum in the near IR range. This result shows that the doping by the Ag element widens the absorption zone from the near IR domain to the visible domain.



Fig.6. Absorbance spectra of CuO thin layers doped with Ag (0%, 5%, 15%, 25% and 50%).

3.5.2. Energy Gap

In order to determine the energy gap of the thin layers prepared by the spin-coating method, the following Tauc equation is used [56]:

$$\alpha h \nu = A \cdot \left(h \nu - E_g \right)^{1/2} \tag{4}$$

with A: Constant, Eg: Optical Gap in eV, hv: energy of a photon eV.

Figure 7 shows the plot of $(\alpha h\nu)^2$ as a function of the energy of a photon $h\nu$. With the extrapolation method, the optical gaps E_g are extracted.



Fig.7.Variation of $(\alpha hv)^2$ as a function of photon energy of Ag doped CuO thin layers.

The energy gap values range from 2.17 eV up to 1.25 eV with an increasing Ag doping rate (Fig.7). This decrease is explained by the fact that doping leads to the displacement of the absorption edge towards lower energies. This is due to an increase in generating energy levels above the valence band. This result confirms that the displacement of Fermi levels towards the valence band (VB) gives to the Ag-doped CuO a P-type semiconductor. This result leads to the absorption of photons of lower energy, and therefore to an increase in transitions electronics and then a decrease in the values of the energy gap.

3.6. Electrical properties

The four-point method is used to measure the electrical conductivity (σ) and electrical resistivity (ρ) of Ag:CuO thin films. The conductivity value is computed using the formula below [48]:

$$\rho = \frac{\Delta v}{l} \cdot e \cdot \frac{\pi}{Ln^2} \tag{5}$$

The electrical conductivity increases with an increase in the case of doped with silver, as the conductivity of the undoped CuO is $3.5.10^{-5}\Omega^{-1}$ ·cm⁻¹, while in the presence of silver it increase until they reach a value of $5.2.10^{-4}\Omega^{-1}$ ·cm⁻¹ for the 50 % Ag:CuO. The resistance values are decreasing in the presence of doping. The results are shown in Table 4.

	e(nm)	$\rho(\mathbf{\Omega} \cdot \mathbf{cm})$	$\sigma(\Omega^{-1} \cdot \mathrm{cm}^{-1})$
CuO pure	320	28016.42	3.5.10 ⁻⁵
5 %Ag :CuO	338	16193.5	6.175 .10 ⁻⁵
15 %Ag :CuO	412	12561.88	7.9.10 ⁻⁵
25 %Ag :CuO	443	4728.45	2.1.10-4
50 %Ag : CuO	670	1922.85	5.2.10-4

Table 4. The electrical parameters obtained by the 4-point method.

Figure 8 shows the variation of conductivity and electrical resistivity of CuO:Ag films as a function of Ag concentration. The results can be due to the evolution of the resistivity for the greatest defect density at the grain boundaries due to the differences in the presence of the atoms of Cu and Ag, and the difference of surface shape. The values of electrical conductivity well agreed with results given in references [56]. It also shows that the conductivity of the samples increases with increasing concentration of silver doping. This observation leads to an increase in the charge carriers responsible for electrical transport. An increase in the electrical conductivity is associated also with an increase in the crystal size and thus a decrease in the grain boundaries, which leads to a decrease in the energy levels and thus the ease of movement of charge carriers. There is an inverse relationship between the crystallite size and energy gap. It can be explained by a quantum confinement size effect [49]. In addition to this effect, the thickness of CuO thin films which acted as the active layer was considered as an important factor for studying the effect on the electrical properties [48].



Fig.8. Variation of conductivity and resistivity as a function of doping ratio by 4 points technique

3.7. Photocatalytic Performance

The optical, structural and morphological characteristics of thin films CuO, 5% Ag:CuO, 15% Ag:CuO, 25% Ag:CuO and 50% Ag:CuO have a significant influence on the photocatalytic performances. The samples are influenced by their band gap, light absorption capacity, crystallinity and surface [57].

Heterogeneous photocatalysis is based on the absorption of photons with energy greater than or equal to the width of the forbidden band ($hv \ge Eg$) of the semiconductor were studied [58]. Such as the electrons which are in the band of valence passed to the band of conduction and smoothed a hole in the band of valence for creation of the pair (e-/h+). In the goal to generate hydroxyl radicals (OH•), holes in the valence band interact with anions (OH⁻). Super oxide radicals •O⁻₂ are formed when electrons in the conduction band interact with oxygen molecules O₂, and gives the transparent solution (Equation 6) which increased when active layers were deposited with low gaps.

•
$$O_2^- + OH$$
•+ Dye \rightarrow mineralization dye (6)

The degradation of OII (1.78.10⁻⁵mol/l; pH=6.44) were tested with the prepared samples under UV irradiation with time duration from one hour up to 5 hours. The figure 10 shows the absorbance spectra corresponding to the photo-degradation in the wavelength range from 350 to 600 nm. All spectra present a maximum at an absorption wavelength of 484 nm corresponding to the wavelength of OII. These spectra represented a decrease in absorption with irradiation time. This result indicates that there is a degradation of dye from a clear color up to a transparent color which confirms that these thin films are active catalysts in the photo catalysis application.

The degradation rate after a time t is calculated using the following formula [59]:

$$D(\%) = \frac{A_0 - A_t}{A_0} \times 100 \tag{7}$$

with A_0 : initial absorption of OII, A_t : absorption at time t (t=1 h to 5 h).

All Ag:CuO catalysis system for each doping concentration represented a significant degradation efficiency in the first three hours. The film doped with 50% Ag represented the fastest catalyst. This result shows that the most efficient in the degradation of this dye, corresponding to the degradation rate after 5 h is ~ 43% (Fig.9e). It represents an increase of almost twice compared to a pure CuO with 27% degradation rate for the same time duration.



Fig.9. Evolution of UV Visible absorption spectra of OII and their degradation as a fonction of irradiation time with UV light in the presence of thin layers (a): CuO, (b): 5% Ag:CuO, (c): 15 %Ag:CuO, (d): 25%Ag :CuO et (e): 50% Ag:CuO.

Figure 10 shows a significant decrease in the A/A_0 ratio for the OII solution as a function of exposure time to UV radiation. The first-order rate constants for OII degradation were estimated using the following equation [58]:

$$A/A_0 = e^{-kt}$$
 (8)

where: k denotes the rate constant, A and A_0 respectively denote initial absorption of OII and absorption at time t (t=1 h to 5 h).

The constant rate for OII dye degradation by pure and 5% doped CuO thin film up to 50% are respectively 6.69.10⁻³ min⁻¹(pH=6.98), 7.03.10⁻³ min⁻¹, 6.55 .10⁻³ min⁻¹, 6.83.10⁻³ min⁻¹ and 8.23.10⁻³ min⁻¹(pH=7.11) respectively. These results illustrate the photocatalytic properties of these layers in the decomposition reaction of OII. The faster degradation rate corresponds to the case of 50% Ag doping and reveals that this film with this doping is the most effective catalyst.



Fig.10. (A/A_0) as a function of the irradiation time in the presence of thin layers of the Ag: CuO.

3.8. Photocatalytic Mechanism

Photocatalysis is an advanced technique that transforms solar energy into sustainable fuels and oxidizes pollutants via the aid of semiconductor photocatalysts. The main scientific and technological challenges for effective photocatalysis are the stability, robustness, and efficiency of semiconductor photocatalysts.

The energy gap of the oxides CuO and Ag₂O, estimated at 2.17 eV and 1.31 eV, respectively, enables them to generate electron/hole pairs (e^{-/h^+}) While absorbing light energy (Eq.1). Doping CuO with Ag resulted in a decrease in recombination and an increase in optical activity in the visual field. Photo-excitation of Ag:CuO nanoparticles caused electrons to transition from the valence band to the conduction band leaving behind holes, which is called oxidation-reduction reactions. Electrons in the conduction band interact with molecular oxygen to produce superoxide radicalions

 $\bullet O_2^-$ and hydroperoxyl radicals $\bullet HO_2^-$ (Eq.2), while holes are trapped in the valence band from

hydroxyl ions to create OH• radicals (Eq.3) [60]. Creation of more OH• and • HO_2^- resulted in high oxidation factors that contributed to the attack and dissociation of the organic dye molecules (Eq.4 and 5) [46, 60]. The separation and migration mechanism of the photo-generated electron/hole pairs of the Ag:CuO sample isillustrated in the figure 11.

Ag₂O electrons can reduce O₂ to •O $_2^-$ due to their positive CB edge potential of -1.16 V with respect to the standard redox potential $E^{\Theta}(O_2/\bullet O_2^-)$ (- 0.33eVvs.NHE) [61]. Thus, the process begins when holes that react with water to produce hydroxide, and electrons react with oxygen to cause a transparent color of the polluted solution. •O $_2^-$ maythen react with H₂O to form •HO₂and H₂O₂ [62]. Moreover, due to the valence band edgel ocation of CuO oxide (+2.39 eV), there is a possibility of dye oxidation to CO₂ and H₂O with CuO through the ementioned holes with respect to thes tandard redox potential $E^{\Theta}(OH^-/\bullet OH)$ (+ 1.99eV vs.NHE) [63]. The position values of two semiconductors at the zero charge point are calculated using the following relations [9, 60]:

$$E_{BV} = X - E_e + 0.5E_g$$
 (9)

$$E_{BC} = E_{BV} - E_g \tag{10}$$

where E_{VB} is the valence band edge potential, E_{CB} the conduction band edge potential, X the value of electronegativity ($X_{CuO} = 5.81 \text{ eV}$ [64], $X_{Ag2O} = 3.99 \text{ eV}$ [65], E_e the energy of free electrons at the hydrogen level (~4.5 eV) and Eg the semiconductor band width. The role of silver doping is very effective compared to the case of CuO. It increases the rate of •OH in a very noticeable way. The formation of holes depends on the chemical nature of Ag:CuO which can explain the high degradation rate of OII in samples with silver doping. The chemical processes are the following:

$$CuO + Ag_2O + h\upsilon \rightarrow CuO (e^{-}) + CuO (h^{+}) + Ag_2O (e^{-}) + Ag_2O (h^{+})$$
(11)



Fig.11.The photocatalytic mechanism of Ag doped CuO thin layers under UV light.

 $h \rightarrow h \rightarrow h$

<u>CuO</u>

Dev

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Conclusion

Thin layers of CuO doped with different percentages of silver (5%, 15%, 25% and 50%) were used to find out their effect as catalysts. A test for the photocatalysis of OII decomposition was done. Thin films were deposited on a glass substrate by sol-gel spin coating method, and the produced films were polycrystalline with a C₂/c space group, with a spectra shift after grafting evidence of a deformation in the copper oxide crystal cell according to XRD data. From SEM results, it was observed that there are pores in the case of Ag doping. Pore number increases with the increase of the doping rate, which gave a very high efficiency and more catalytic surfaces. The creation of pores on the surface of the sample contributed to the deposition of a larger amount of impurities of the polluted solution, which enabled a faster decomposition of the OII dye compared to thin films of pure CuO. This is well confirmed with results of the energy gap which decreases with the increase of the rate of doping due to the increase in energy levels that gives a greater conductivity.

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